#### Forces and Relaxation

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#### • Literature:

- S.O. Kasap "Principles of Electronic Materials and Devices"
- D. Marx, J. Hutter "Ab Initio Molecular Dynamics"
- R. Martin "Electronic Structure"



#### Forces and Relaxation

• For this lecture: Classical nuclei, quantum-mechanical electrons



- $\bullet$  Simple example:  $H_2^+$  molecule
- More complicated: Potential Energy surface in solids
- In practice: DFT to solve the underlying QM problem
- In practice: Forces within DFT
- Context: Problems and Applications

# Multiple Nuclei: What causes Forces?

- Simplest system with multiple nuclei is the H<sub>2</sub><sup>+</sup> ion
- Two nuclei (protons), one electron
- Exact solution: from Schrödinger Equation in 3D

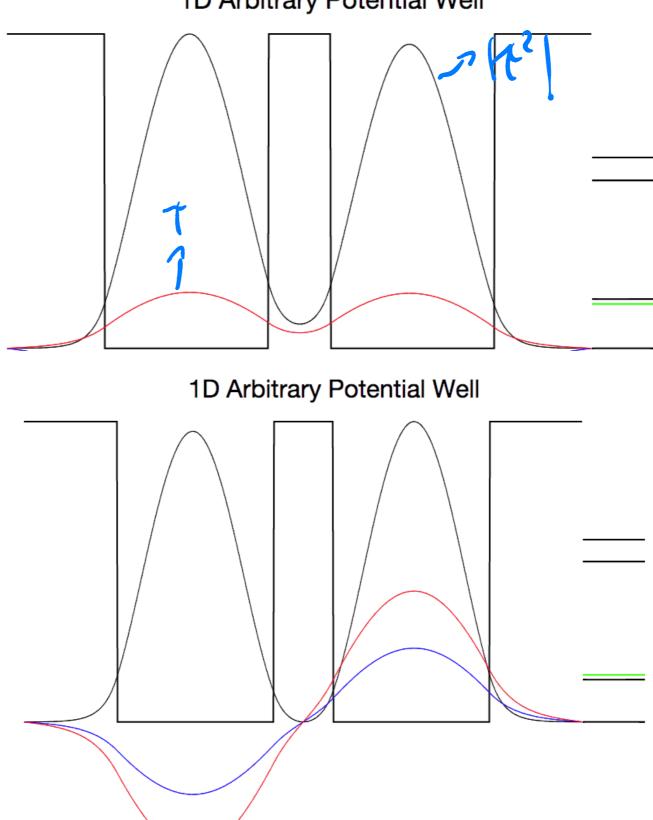
$$\hat{H} = \left(\hat{T}_{el} + \hat{V}_{ab} + \hat{V}_a + \hat{V}_b\right)$$

- Here: approach the problem in several steps
- First step: 1D and well potentials

$$\left(-\frac{\hbar^2}{2m}\Delta - \frac{e^2}{4\pi\epsilon_0 r_a} - \frac{e^2}{4\pi\epsilon_0 r_b}\right)\psi = E\psi$$

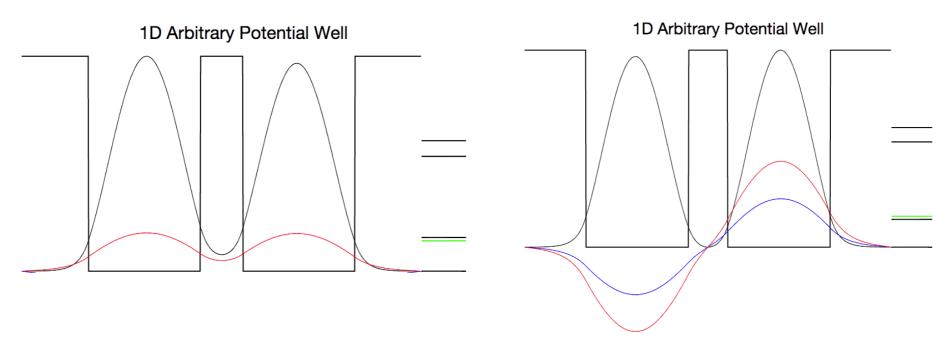
# Multiple Nuclei: Introduction

1D Arbitrary Potential Well



# Multiple Nuclei: Introduction

- Here: approach the problem in several steps
- First step: 1D and well potentials



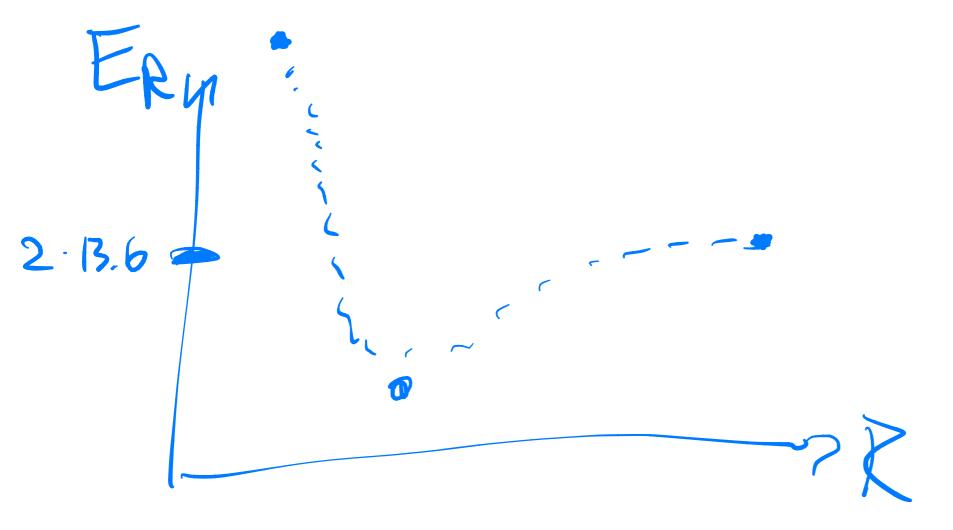
• Second step: 1D and Coulomb potentials

### Multiple Nuclei: What causes Forces?

• QM: Solution from Schrödinger equation:

$$\hat{H}\psi = E\psi$$
$$\hat{H}_{\mathbf{R}}(\mathbf{r})\psi_{\mathbf{R}}(\mathbf{r}) = E_{\mathbf{R}}\psi_{\mathbf{R}}(\mathbf{r})$$

• Thought experiment for H<sub>2</sub> molecule:

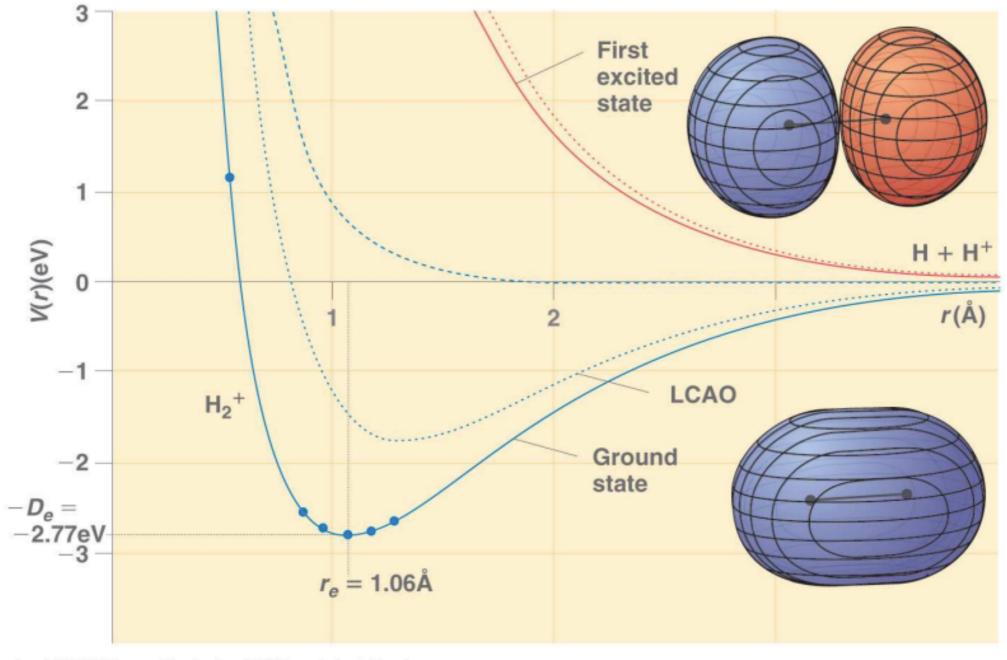


### Multiple Nuclei: H<sub>2</sub><sup>+</sup> ion

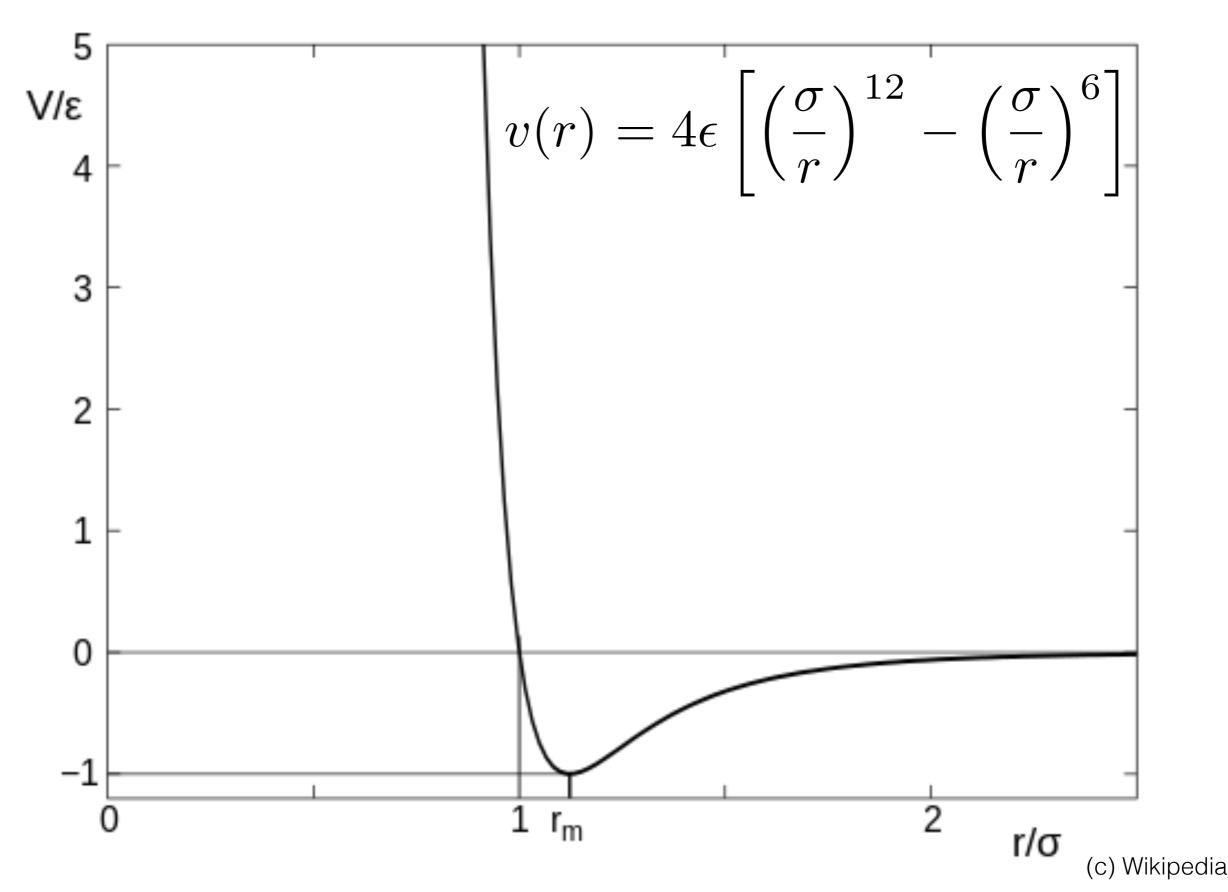
• what we plot here:

$$\hat{H}\psi = E\psi$$

$$\hat{H}_{\mathbf{R}}(\mathbf{r})\psi_{\mathbf{R}}(\mathbf{r}) = E_{\mathbf{R}}\psi_{\mathbf{R}}(\mathbf{r})$$

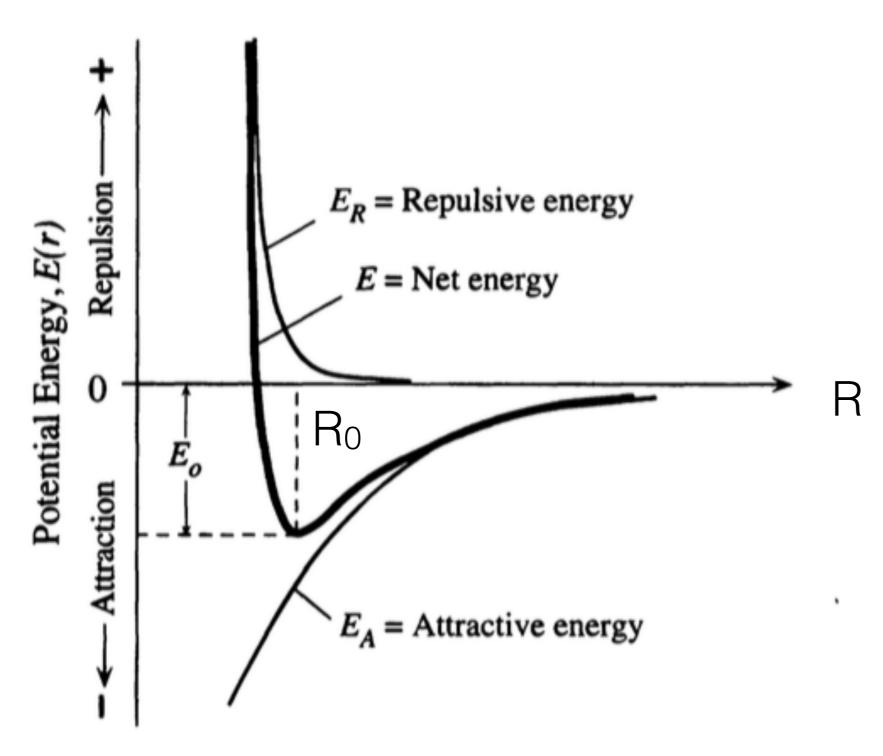


### Analytical example: Lennard Jones Potential



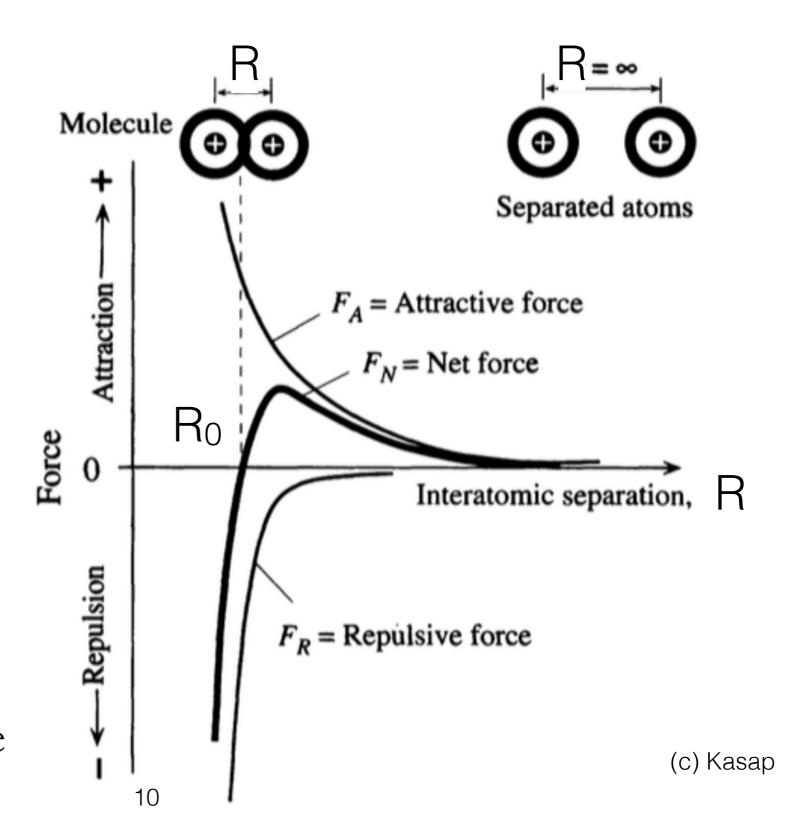
### Multiple Nuclei: What causes Forces?

• total energy can be viewed as sum of an attractive term and a repulsive term



# Bonding in Solids: Forces

- Force follows from energy:  $F(\mathbf{R}) = -\nabla E(\mathbf{R})$
- Equilibrium separation: Bond length R<sub>0</sub>
- Energy at that length: Bonding energy
- this overall picture works also for solids
- we can even use it to derive thermal expansion and bulk modulus
- (strong) directional dependence possible: Potential energy surface

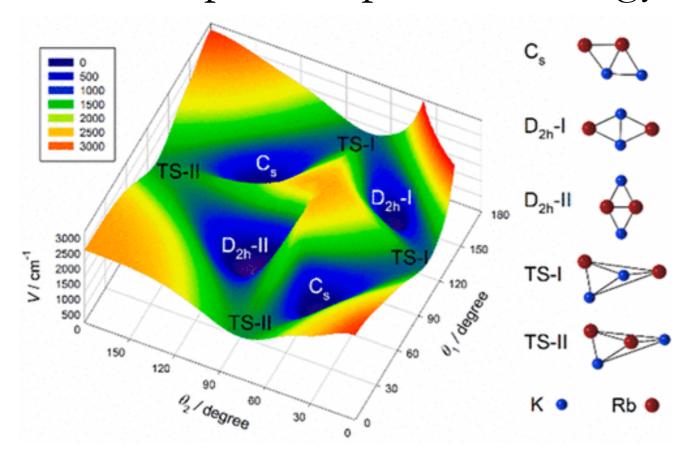


### Bonding in Solids: Quantum Mechanics

• More complicated for solids, but the concept of a "potential energy surface" holds; solve:

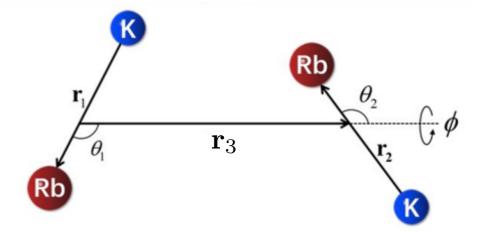
$$\hat{H}_{\mathbf{R}}(\mathbf{r})\psi_{\mathbf{R}}(\mathbf{r}) = E_{\mathbf{R}}\psi_{\mathbf{R}}(\mathbf{r})$$

• Example of a potential energy surface:



(c) J. Phys. Chem. Lett. 2020, 11, 7, 2605-2610

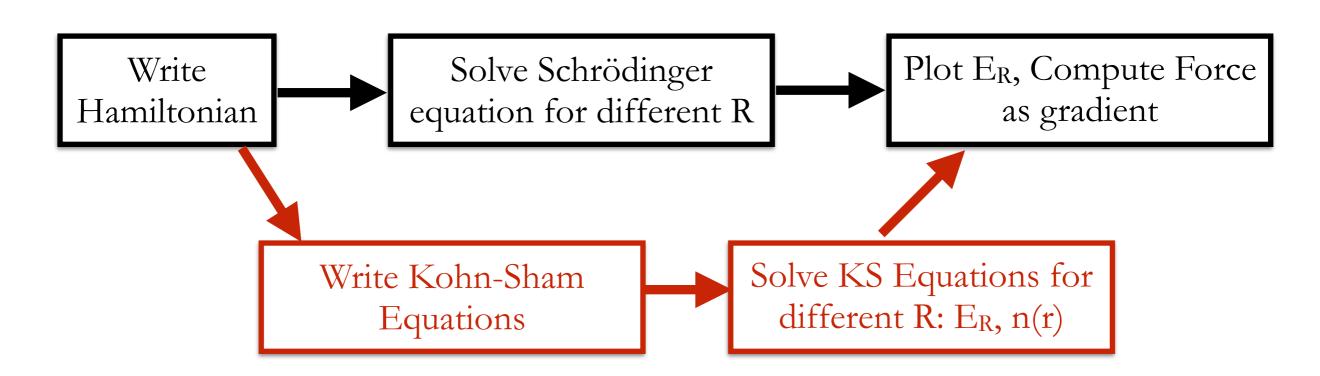
• Forces from gradient!



- 6 variables: Bond lengths and angles, hence a 6D potential energy surface
- Only 2 variables shown
- Pronounced directional dependence visible

#### Forces and Relaxation

- Simple example: H<sub>2</sub><sup>+</sup> molecule
- More complicated: Potential Energy surface in solids
- In practice: DFT to solve the underlying QM problem
- In practice: Forces within DFT
- Context: Problems and Applications



# Forces in DFT: Hellmann-Feynman Theorem

• Still need to actually compute the forces, here within DFT

$$\mathbf{F}_I = -\nabla_I \langle \Psi_0 | \mathcal{H}_e | \Psi_0 \rangle = -\nabla E(\mathbf{R})$$

- Finite-difference method costly and inaccurate
- Instead: Analytical evaluation:

$$\nabla_I \langle \Psi_0 | \mathcal{H}_{
m e} | \Psi_0 \rangle =$$

$$\langle \Psi_0 | \nabla_I \mathcal{H}_e | \Psi_0 \rangle + \langle \nabla_I \Psi_0 | \mathcal{H}_e | \Psi_0 \rangle + \langle \Psi_0 | \mathcal{H}_e | \nabla_I \Psi_0 \rangle$$

• Hellmann-Feynman theorem says:

$$\mathbf{F}_I^{\mathrm{HFT}} = - \langle \Psi_0 | \nabla_I \mathcal{H}_{\mathrm{e}} | \Psi_0 \rangle$$

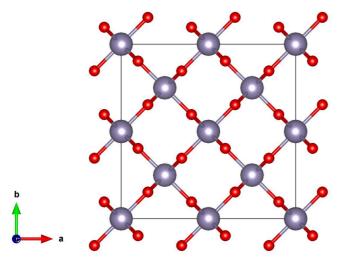
... if wave function is an exact eigenfunction

#### Forces in DFT: Forces on atoms

• DFT total energy:  $E_{\rm tot} = E_{\rm kin} + E_{\rm loc}^{\rm PP} + E_{\rm nloc}^{\rm PP} + E_{\rm xc} + E_{\rm ES}$ 

$$\frac{\partial E_{\text{tot}}}{\partial R_{I,s}} = \frac{\partial E_{\text{loc}}^{\text{PP}}}{\partial R_{I,s}} + \frac{\partial E_{\text{nloc}}^{\text{PP}}}{\partial R_{I,s}} + \frac{\partial E_{\text{ES}}}{\partial R_{I,s}}$$

- Evaluate derivatives analytically; leads to expressions in terms of electron density+plane-wave coefficients (see Marx, Hutter)
- These are implemented in DFT codes
- Use this to "relax" atomic positions, i.e. move until F=0



- Unit cell unchanged here (no change in shape and size)
- Update positions of the atoms in the cell using, e.g., gradient descent
- Tip: Relaxation can be slow (Plot forces, change stepsize)

### Forces in DFT: Forces on cells, Stress tensor

• If simulation cell is changed (in shape or size), electronic internal stress tensor is required:

$$\Pi_{uv} = -\frac{1}{\Omega} \sum_{s} \frac{\partial E_{\mathrm{tot}}}{\partial h_{us}} h_{sv}^{\mathrm{T}} \qquad \mathbf{h} = [\mathbf{a}_1, \mathbf{a}_2, \mathbf{a}_3]$$

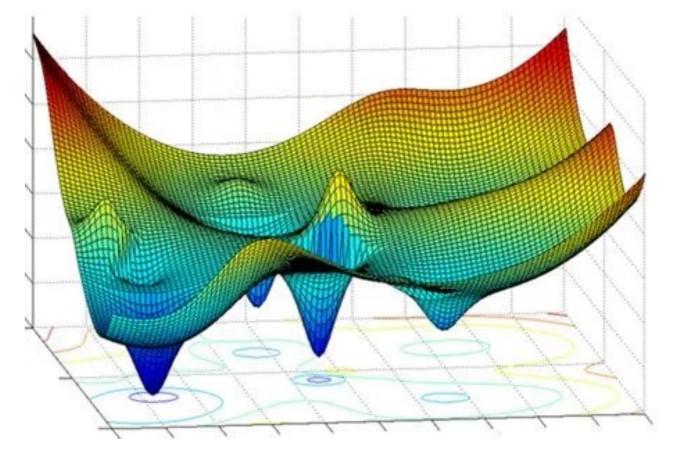
• Using total energy from previous slide:

$$\frac{\partial E_{\text{tot}}}{\partial h_{uv}} = \frac{\partial E_{\text{kin}}}{\partial h_{uv}} + \frac{\partial E_{\text{loc}}^{\text{PP}}}{\partial h_{uv}} + \frac{\partial E_{\text{nloc}}^{\text{PP}}}{\partial h_{uv}} + \frac{\partial E_{\text{xc}}}{\partial h_{uv}} + \frac{\partial E_{\text{xc}}}{\partial h_{uv}} + \frac{\partial E_{\text{ES}}}{\partial h_{uv}}$$

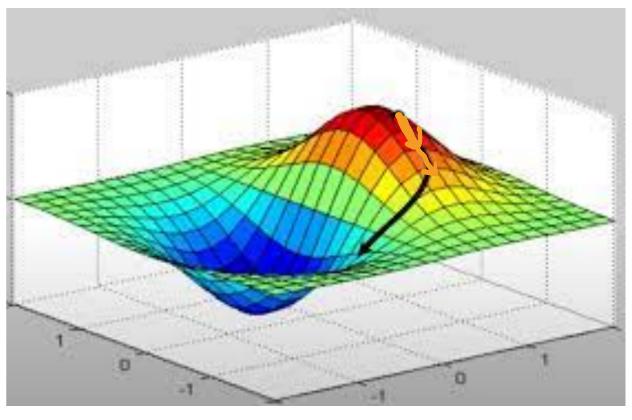
- Also do these analytically; again expressions in density and plane-wave basis set (see Marx+Hutter for explicit equations)
- Implemented in DFT codes; with these, cell shape and cell volume can be relaxed (until external stress=0)
- Tip: Larger plane-wave cutoff required to achieve convergence (larger than your previous test of total-energy convergence)

#### **Problems: Local Minima**

- Potential-energy surface can be complicated
- Many local minima, only one global minimum
- "Relaxation" to find the global minimum
- Gradient descent approach can get stuck in local minimum
- Tips: (i) Change step size, (ii) Smart schemes to determine descent direction (BFGS), (iii) Break symmetry



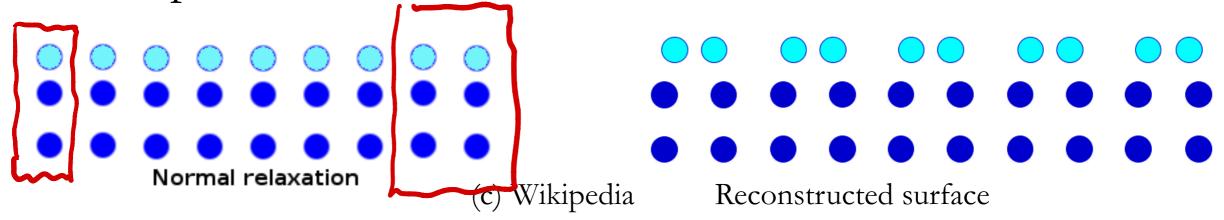
(c) https://medium.com/@ellie.arbab/maths-of-word-to-vec-8af5d9c263f2



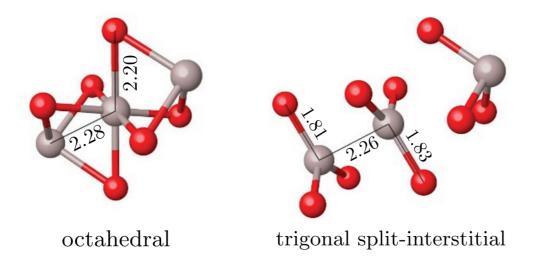
(c) https://mriquestions.com/back-propagation.html

### Problems: Symmetry Breaking

- Problem: Ground-state geometry is not necessarily "obvious"
- Caution: It does not have to fit a primitive (or simple) unit cell
- Example: Surface reconstruction:



• Example: Defect atomic geometries:



Neutral aluminum interstitial geometry in Al<sub>2</sub>O<sub>3</sub>; Energies differ by more than 1 eV; (c) J. Phys.: Cond. Mat. **35**, 334002 (2023)

• Tip: Try different unit cell sizes (even for bulk!) and distort/break the ideal symmetry (e.g. Voronoi method)

### Problems: Pulay Forces

• Started with:  $\nabla_I \langle \Psi_0 | \mathcal{H}_e | \Psi_0 \rangle =$ 

$$\langle \Psi_0 | \nabla_I \mathcal{H}_e | \Psi_0 \rangle + \langle \nabla_I \Psi_0 | \mathcal{H}_e | \Psi_0 \rangle + \langle \Psi_0 | \mathcal{H}_e | \nabla_I \Psi_0 \rangle$$

• Hellmann-Feynman theorem:

$$\mathbf{F}_I^{ ext{HFT}} = - \left< \Psi_0 \middle| 
abla_I \mathcal{H}_{ ext{e}} \middle| \Psi_0 
ight>$$

... true if wave function is an exact eigenfunction

- Also true for variational wave functions, if complete basis is used, which is rarely the case
- Expand Slater determinant into basis functions

$$\phi_i = \sum_{\nu} c_{i\nu} f_{\nu}(\mathbf{r}; \{\mathbf{R}_I\})$$

• For the variation of the wave function, the gradient yields:

$$\nabla_I \phi_i = \sum_{\nu} (\nabla_I c_{i\nu}) f_{\nu}(\mathbf{r}; \{\mathbf{R}_I\}) + \sum_{\nu} c_{i\nu} (\nabla_I f_{\nu}(\mathbf{r}; \{\mathbf{R}_I\}))$$

• Allows to write:  $\mathbf{F}_I = \mathbf{F}_I^{\mathrm{HFT}} + \mathbf{F}_I^{\mathrm{IBS}} + \mathbf{F}_I^{\mathrm{NSC}}$ 

**Problems: Pulay Forces** 

$$\mathbf{F}_I = \mathbf{F}_I^{\mathrm{HFT}} + \mathbf{F}_I^{\mathrm{IBS}} + \mathbf{F}_I^{\mathrm{NSC}}$$

- Pulay force vanishes exactly if origin-less basis (e.g. plane waves) are used and the number of basis functions is kept fixed (careful when the volume of your cell changes!)
- For other basis sets: Pulay needs to be included explicitly
- Non-selfconsistency error can be made small by achieving high self consistency  $|\langle \phi_0 | \phi_0 \rangle|^2 = n_0$

$$H[n_i] |\phi_{i+1}\rangle = E |\phi_{i+1}\rangle$$

$$|\langle \phi_{i+1} | \phi_{i+1} \rangle|^2 = n_{i+1}$$

• Tip: Pulay corrections (likely already implemented or not needed (plane waves)); high accuracy criterion for self-consistency

# Applications: Ab-Initio Molecular dynamics

- Disclaimer: Details by Sara Bonella, Monday at 11 am
- Basic idea: Let's do statistical mechanics ( $T_{latt} > 0$  K)! (Instead of relaxing/finding minimum energy configuration)
- ullet Come up with initial conditions and propagate F=ma
- Molecular Dynamics:
  - Compute force F
  - Move ions/nuclei according to F=ma (using e.g. Verlet scheme for Newton's equations of motion)
  - Repeat
- Classical MD: Use classical (analytical or ML) potentials for F
- Ab-initio MD: Find DFT ground state at each step and compute F (as done on previous slides)

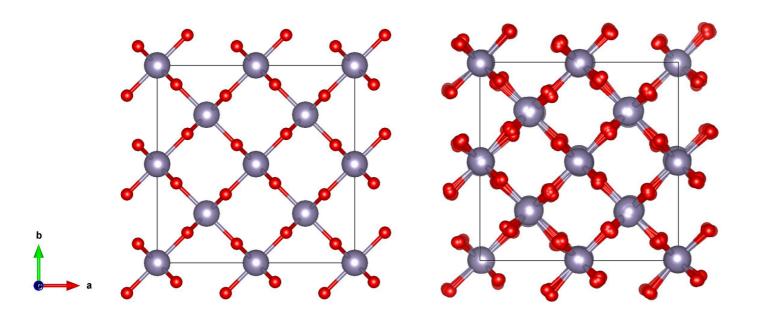
# Applications: Ehrenfest dynamics

- Ab-initio MD: Find DFT ground state at each step and compute F
- Ehrenfest dynamics: Force does not need to be computed from an electronic ground state!
- If you have a time-dependent electron density n(t), e.g. from time-dependent DFT, you can use Hellmann-Feynman theorem and proceed as discussed on previous slide
- n(t) is not a ground state, but an excited-state density
- Applications include, for instance, radiation damage problems

AIMD	Nuclei	Electronic structure
ВО	$M_I \mathbf{\ddot{R}}_I(t) = -  abla_I \min_{\{\phi_i\}} \left\{ \left<\Psi_0 \left  H_\mathrm{e}  ight  \Psi_0  ight>  ight\}$	$0 = -H_{ m e}\phi_i + \sum_j \Lambda_{ij}\phi_j$
E	$M_I \mathbf{\ddot{R}}_I(t) = -  abla_I \left\langle \Psi_0 \left  H_\mathrm{e}  ight  \Psi_0  ight angle$	$i\hbar\dot{\Psi}_0(t)=H_{ m e}\Psi_0$

# **Applications: Phonons**

• Disclaimer: Details by Cyrus Dreyer, Friday at 8.30 am



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FIG. 1. Supercell geometries used in our simulations for T=0 K (left) and for T=300 K (right), where 10 configurations are superimposed for visualization.

- Harmonic force constants:  $\frac{d^2E}{dx_i dx_j}$
- Harmonic eigenfrequencies are eigenvalues of dynamic matrix:

$$D_{I\alpha,J\beta} = \frac{1}{\sqrt{M_I M_J}} \frac{\partial^2 E_{KS}}{\partial R_{I\alpha} \partial R_{J\beta}}$$

Predict phonon frequencies!

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  - R. Martin "Electronic Structure"

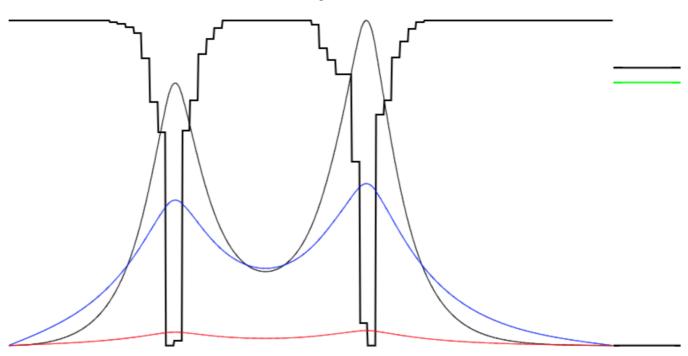






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1D Arbitrary Potential Well



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